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### **SPECIFICATION**

CUSTOM	ER :							
MODULE	NO.:	WH1602A-YGH-CTK						
APPROVI								
SALES BY	APPROVED	BY	CHECKED BY	PREPARED BY				
ISSUED DATE:								



MODLE NO:

REC	ORDS OF REV	ISION		DOC. FIRST ISSUE
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0	2004.07.30		Fi	rst issue

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### 1. Module Classification Information

Brand: WINSTAR DISPLAY CORPORATION

Display Type: H→ Character Type, G→ Graphic Type

**f** Display Font: Character 16 words, 2Lines.

" Model serials no.

··· Backlight Type : N→ Without backlight

 $B\rightarrow EL$ , Blue green  $A\rightarrow LED$ , Amber

 $D\rightarrow EL$ , Green  $R\rightarrow LED$ , Red

 $W\rightarrow$  EL, White  $O\rightarrow$  LED, Orange

 $F\rightarrow$  CCFL, White  $G\rightarrow$  LED, Green

Y→ LED, Yellow Green

† LCD Mode:  $B \rightarrow TN$  Positive, Gray  $T \rightarrow FSTN$  Negative

N→ TN Negative,

G→ STN Positive, Gray

Y→ STN Positive, Yellow Green

M→ STN Negative, Blue

J→ Reflective, W. T, 12:00

F→ FSTN Positive

**‡** LCD Polarize A→ Reflective, N.T, 6:00 H→ Transflective, W.T,6:00

range/ View D→ Reflective, N.T, 12:00 direction C Reflective, W.T. 6:00

G→ Reflective, W. T, 6:00 C→ Transmissive, N.T,6:00

K→ Transflective, W.T,12:00

F→ Transmissive, N.T,12:00

B→ Transflective, N.T,6:00 I→ Transmissive, W. T, 6:00

E→ Transflective, N.T.12:00 L→ Transmissive, W.T,12:00

Special Code CT: English and Cyrillic standard font; K: LED 20 DICE

### 2.Precautions in use of LCD Modules

- (1)Avoid applying excessive shocks to the module or making any alterations or modifications to it.
- (2)Don't make extra holes on the printed circuit board, modify its shape or change the components of LCD module.
- (3)Don't disassemble the LCM.
- (4)Don't operate it above the absolute maximum rating.
- (5)Don't drop, bend or twist LCM.
- (6) Soldering: only to the I/O terminals.
- (7)Storage: please storage in anti-static electricity container and clean environment.

### 3.General Specification

Item	Dimension	Unit
Number of Characters	16 characters x 2 Lines	-
Module dimension	84.0 x 44.0 x 13.5(MAX)	mm
View area	66.0 x 16.0	mm
Active area	56.20 x 11.5	mm
Dot size	0.55 x 0.65	mm
Dot pitch	0.60 x 0.70	mm
Character size	2.95 x 5.55	mm
Character pitch	3.55 x 5.95	mm
LCD type	STN, Positive, Transflective, Gray	- 1
Duty	1/16	

View direction	6 o'clock
Backlight Type	LED Yellow green

# 4. Absolute Maximum Ratings

Item	Symbol	Min	Тур	Max	Unit
Operating Temperature	$T_{\mathrm{OP}}$	-20	-	+70	°C
Storage Temperature	$T_{\mathrm{ST}}$	-30	-	+80	°C
Input Voltage	V <sub>I</sub>	$V_{SS}$	-	$V_{ m DD}$	V
Supply Voltage For Logic	$V_{ m DD} ext{-}V_{ m SS}$	-0.3	-	7	V
Supply Voltage For LCD	$V_{ m DD} ext{-}V_0$	-0.3	-	13	V

# 5.Electrical Characteristics

Item	Symbol	Condition	Min	Тур	Max	Unit
Supply Voltage For Logic	$ m V_{DD} ext{-}V_{SS}$	-	4.5	-	5.5	V
		Ta=-20°C	-	-	5.2	V
upply Voltage For LCD	$V_{DD}$ - $V_0$	Ta=25°C	-	3.8	-	V
		Ta=70°C	3.2	-	-	V
Input High Volt.	$V_{\mathrm{IH}}$	-	2.2	-	$V_{DD}$	V

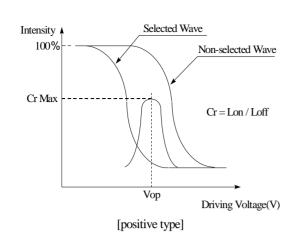
Input Low Volt.	$V_{\rm IL}$	-	-	-	0.6	V
Output High Volt.	$V_{\mathrm{OH}}$	-	2.4	-	-	V
Output Low Volt.	$V_{ m OL}$	-	-	-	0.4	V
Supply Current	$I_{\mathrm{DD}}$	V <sub>DD</sub> =5V	-	1.2	-	mA

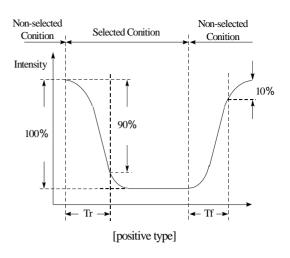
# 6.Optical Characteristics

Item	Symbol	Condition	Min	Тур	Max	Unit
View Angle	(V)θ	CR≧ 2	20	-	40	deg
	(Н)ф	CR≧ 2	-30	-	30	deg
Contrast Ratio	CR	1	ı	3	ı	-
Response Time	T rise	1	ı	150	200	ms
1	T fall	-	1	150	200	ms

**Definition of Operation Voltage (Vop)** 

Definition of Response Time (  $\mbox{Tr}$  ,  $\mbox{Tf}$  )



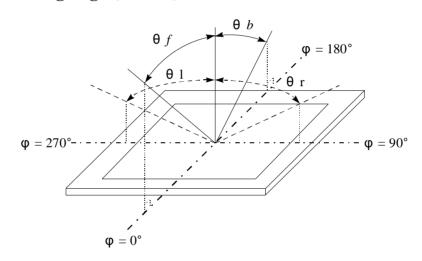


#### **Conditions:**

Operating Voltage: Vop Viewing Angle( $\theta$ ,  $\varphi$ ):  $0^{\circ}$ ,  $0^{\circ}$ 

Frame Frequency: 64 HZ Driving Waveform: 1/N duty, 1/a bias

### **Definition of viewing angle(CR≥ 2)**

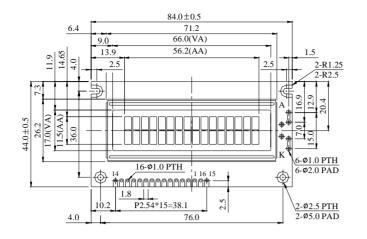


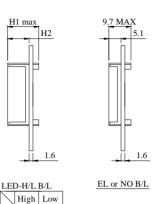
# 7.Interface Pin Function

Pin No.	Symbol	Level	Description
1	$V_{SS}$	0V	Ground
2	$V_{\mathrm{DD}}$	5.0V	Supply Voltage for logic
3	VO	(Variable)	Operating voltage for LCD
4	RS	H/L	H: DATA, L: Instruction code
5	R/W	H/L	H: Read(MPU→ Module) L: Write(MPU→ Module)
6	E	H,H→ L	Chip enable signal

7	DB0	H/L	Data bit 0
8	DB1	H/L	Data bit 1
9	DB2	H/L	Data bit 2
10	DB3	H/L	Data bit 3
11	DB4	H/L	Data bit 4
12	DB5	H/L	Data bit 5
13	DB6	H/L	Data bit 6
14	DB7	H/L	Data bit 7
15	A	-	LED +
16	K	-	LED -

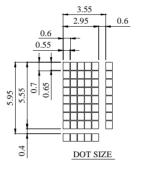
# 8.Contour Drawing & Block Diagram



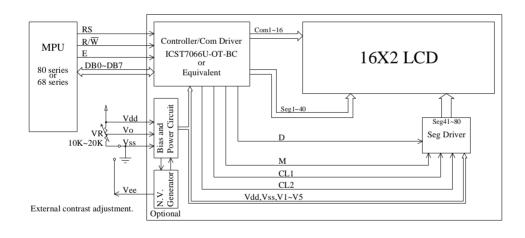


H1 13.5 12.1 H2 8.9 7.5





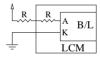
The non-specified tolerance of dimension is  $\pm 0.3$ mm.



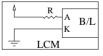
LED B/L Drive Method 1.Drive from A,K



2.Drive from pin15, pin16



(Will never get Vee output from pin15) 3.Drive from Vdd,Vss



(Contrast performance may go down.)

#### Recommanded Value

- (1)  $V_{\text{LED}}$ = 4.2V,  $I_{\text{LED}}$ = 130mA R= 6.2 $\Omega$  (1/2 Watt)
- $(2) \ V_{\text{LED}}{=}\ 4.0V, \ I_{\text{LED}}{=}\ 20mA$   $R{=}\ 40\Omega\ (1/2\ Watt)$

Character located 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 DDRAM address 00 01 02 03 04 05 06 07 08 09 0A 0B 0C 0D 0E 0F DDRAM address 40 41 42 43 44 45 46 47 48 49 4A 4B 4C 4D 4E 4F

# 9. Function Description

The LCD display Module is built in a LSI controller, the controller has two 8-bit registers, an instruction register (IR) and a data register (DR).

The IR stores instruction codes, such as display clear and cursor shift, and address information for display data RAM (DDRAM) and character generator (CGRAM). The IR can only be written from the MPU. The DR temporarily stores data to be written or read from DDRAM or CGRAM. When address information is written into the IR, then data is stored into the DR from DDRAM or CGRAM. By the register selector (RS) signal, these two registers can be selected.

RS	R/W	Operation
0	0	IR write as an internal operation (display clear, etc.)
0	1	Read busy flag (DB7) and address counter (DB0 to DB7)
1	0	Write data to DDRAM or CGRAM (DR to DDRAM or CGRAM)
1	1	Read data from DDRAM or CGRAM (DDRAM or CGRAM to DR)

#### Busy Flag (BF)

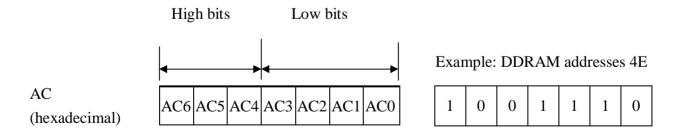
When the busy flag is 1, the controller LSI is in the internal operation mode, and the next instruction will not be accepted. When RS=0 and R/W=1, the busy flag is output to DB7. The next instruction must be written after ensuring that the busy flag is 0.

#### Address Counter (AC)

The address counter (AC) assigns addresses to both DDRAM and CGRAM

#### **Display Data RAM (DDRAM)**

This DDRAM is used to store the display data represented in 8-bit character codes. Its extended capacity is 80×8 bits or 80 characters. Below figure is the relationships between DDRAM



addresses and positions on the liquid crystal display.

#### Display position DDRAM address

1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16

00	01	02	03	04	05	06	07	08	09	0A	0B	0C	0D	0E	0F
40	41	42	43	44	45	46	47	48	49	4A	4B	4C	4D	4E	4F

2-Line by 16-Character Display

#### **Character Generator ROM (CGROM)**

The CGROM generate 5×8 dot or 5×10 dot character patterns from 8-bit character codes. See Table 2.

#### **Character Generator RAM (CGRAM)**

In CGRAM, the user can rewrite character by program. For 5×8 dots, eight character patterns can be written, and for 5×10 dots, four character patterns can be written.

Write into DDRAM the character code at the addresses shown as the left column of table 1. To show the character patterns stored in CGRAM.

# Relationship between CGRAM Addresses, Character Codes (DDRAM) and Character patterns

Table 1.

For 5 \* 8 dot character patterns

Character Codes (DDRAM data)	CGRAM Address	Character Patterns (CGRAM data)	
7 6 5 4 3 2 1 0	5 4 3 2 1 0	7 6 5 4 3 2 1 0	
High Low	High Low	High Low	
0 0 0 0 * 0 0 0	0 0 0 0 0 0 0 0 1 0 1 0 0 1 1 0 0 1 1 0 0 1 1 1 1 1 1 0 1 1 1 1 1 0 1	* * * * * * * * * * * * * * * * * * *	Character pattern(1)
0 0 0 0 * 0 0 1	0 0 0 0 0 0 0 1 0 1 0 0 1 1 0 0 1 1 1 0 1 1 1 1 0 1 1 1 1 0 1 1 1 1 0 1 1 1 1 1 0 1	* * * * 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	Character pattern(2)
	$\begin{bmatrix} 0 & 0 & 0 \\ 0 & 0 & 1 \end{bmatrix}$	* * *	
0 0 0 0 * 1 1 1	1 1 1 1 0 0 1 0 1 1 1 0 1 1 1	* * *	

For 5 \* 10 dot character patterns

<u> </u>	1	U	uО	ı cı	n a i	a c	ter	P	at	terr	18															_	
						o d d a t					CG	R	A M	I A	d d	res	SS	_		act R A							
7	7	6	5	4	3	2	1	l	0			5	4	3	2	1	0	7	6	5	4	3	2	1	0		
		Ні	gh			Lo	w				Н	i g l	h		Lo	w			Нi	gh		L	ov	7			
														0	0	0	0	*	*	*	0	0	0	0	0	1	Ī
														0	0	0	1	*	*	*	0	0	0	0	0		
														0	0	1	0	*	*	*		0			0		
														0	0	1	1	*	*	*			0	0			
														0	1	0	0	*	*	*		0	0	0			
0		0	0	0	*	0	0	)	0			0	0	0	1	0	1	*	*	*		0	0	0			
														0	1	1	0	*	*	*					0		Character
														0	1	1	1	*	*	*		0	0	0	0		pattern
														1	0	0	0	*	*	*		0	0	0	0		
														1	0	0	1	*	*	*		0	0	0	0	,	
														1	0	1	0	*	*	*	0	0	0	0	0		Cursor pattern
																			Î								
														1	1	1	1	*	*	*	*	*	*	*	*		

■ : " High "

# 10.Character Generator ROM Pattern

#### Table.2

Upper 4 bit																
Lower 4 bit	LLLL	LLLH	LLHL	LLHH	LHLL	LHLH	LHHL	LHHH	HLLL	HLLH	HLHL	HLHH	HHLL	HHLH	HHHL	нннн
LLLL	CG RAM (1)							====					=	=		
LLLH	CG RAM (2)		-	-1				-:::			=====	::::		=		
LLHL	CG RAM (3)		11	- " ;				:					1	::		
LLHH	CG RAM (4)				====		====	-:::-				<b></b> :		::		
LHLL	CG RAM (5)		[									::	i			
LHLH	CG RAM (6)		•••	*				ii				•				
LHHL	CG RAM (7)		:::.			ii		ii								
LHHH	CG RAM (8)							ii			.!!	::::	-:::	::.	-	
HLLL	CG RAM (1)							-:-: <u>-</u>				<b>.</b> [	-:]-;		-	
HLLH	CG RAM (2)					= = =					:: ::		:-]:-			
HLHL	CG RAM (3)		-[-:	==	!							<b>!-:</b> :	:: ::	•••••		
НЦНН	CG RAM (4)			==												
HHLL	CG RAM (5)		<b>:</b> =	•:-										-		
ННГН	CG RAM (6)						! · · !				1	<b></b>	•			
нннг	CG RAM (7)		==													
нннн	CG RAM (8)						::							==	<b></b>	

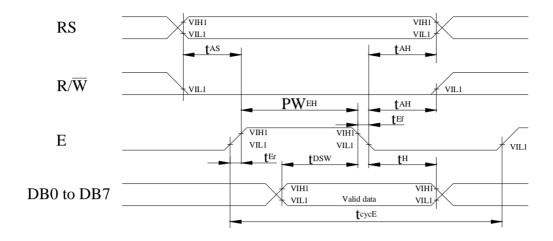
# 11.Instruction Table

Instruction				Ins	structi	ion Co	ode		Description	Execution time			
Instruction	RS	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0	Description	(fosc=270Khz)	
Clear Display	0	0	0	0	0	0	0	0	0	1	Write "00H" to DDRAM and set DDRAM address to "00H" from AC	1.53ms	
Return Home	0	0	0	0	0	0	0	0	1	-	Set DDRAM address to "00H" from AC and return cursor to its original position if shifted. The contents of DDRAM are not changed.	1.53ms	
Entry Mode Set	0	0	0	0	0	0	0	1	I/D	SH	Assign cursor moving direction and enable the shift of entire display.	39µ s	
Display ON/OFF Control	0	0	0	0	0	0	1	D	С	В	Set display (D), cursor (C), and blinking of cursor (B) on/off control bit.	39µ s	
Cursor or Display Shift	0	0	0	0	0	1	S/C	R/L	-	-	Set cursor moving and display shift control bit, and the direction, without changing of DDRAM data.	39µ s	
Function Set	0	0	0	0	1	DL	N	F	-	-	Set interface data length (DL:8-bit/4-bit), numbers of display line (N:2-line/1-line)and, display font type (F:5×11 dots/5×8 dots)	39µ s	
Set CGRAM Address	0	0	0	1	AC5	AC4	AC3	AC2	AC1	AC0	Set CGRAM address in address counter.	39µ s	
Set DDRAM Address	0	0	1	AC6	AC5	AC4	AC3	AC2	AC1	AC0	Set DDRAM address in address counter.	39µ s	
Read Busy Flag and Address	0	1	BF	AC6	AC5	AC4	AC3	AC2	AC1	AC0	Whether during internal operation or not can be known by reading BF. The contents of address counter can also be read.	0μ s	
Write Data to RAM	1	0	D7	D6	D5	D4	D3	D2	D1	D0	Write data into internal RAM (DDRAM/CGRAM).	43µ s	
Read Data from RAM	1	1	D7	D6	D5	D4	D3	D2	D1	D0	Read data from internal RAM (DDRAM/CGRAM).	43µ s	

\* " - " : don't care

# 12. Timing Characteristics

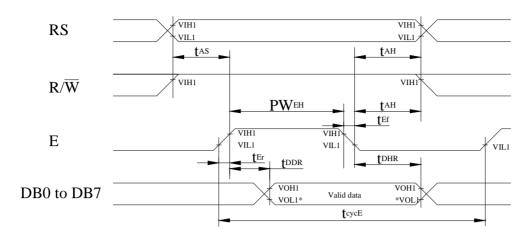
### 12.1 Write Operation



Ta=25°C,  $VDD=5.0\pm0.5V$ 

Item	Symbol	Min	Тур	Max	Unit
Enable cycle time	$t_{\rm cycE}$	400	1	1	ns
Enable pulse width (high level)	$PW_{EH}$	150	-	-	ns
Enable rise/fall time	$t_{\rm Er}, t_{\rm Ef}$	-	-	25	ns
Address set-up time (RS, R/W to E)	$t_{AS}$	30	-	-	ns
Address hold time	$t_{AH}$	10	-	-	ns
Data set-up time	$t_{ m DSW}$	40	-	-	ns
Data hold time	t <sub>H</sub>	10	-	-	ns

### 12.2 Read Operation

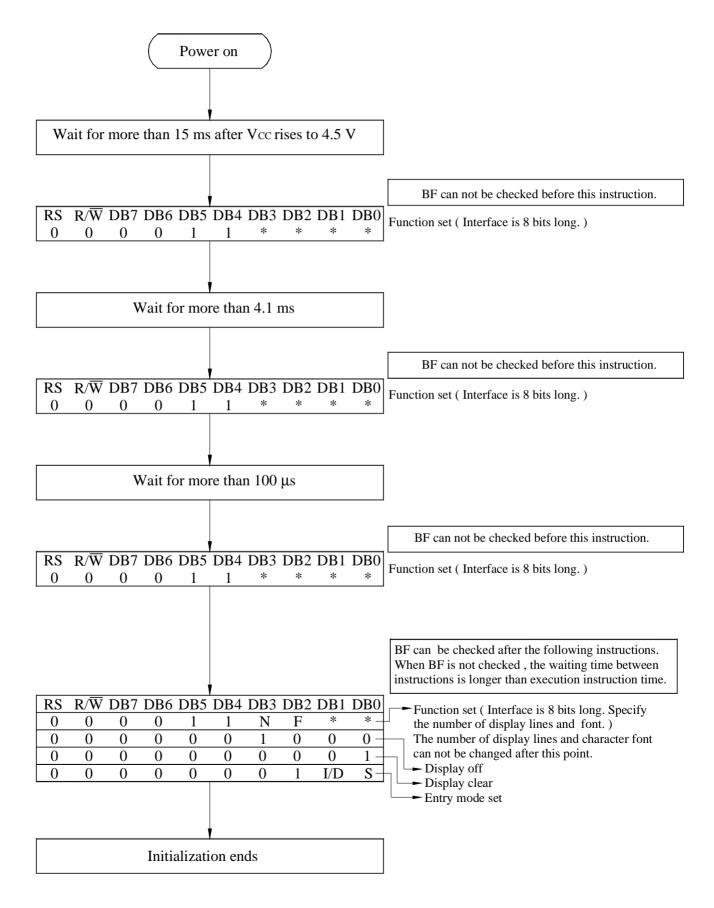


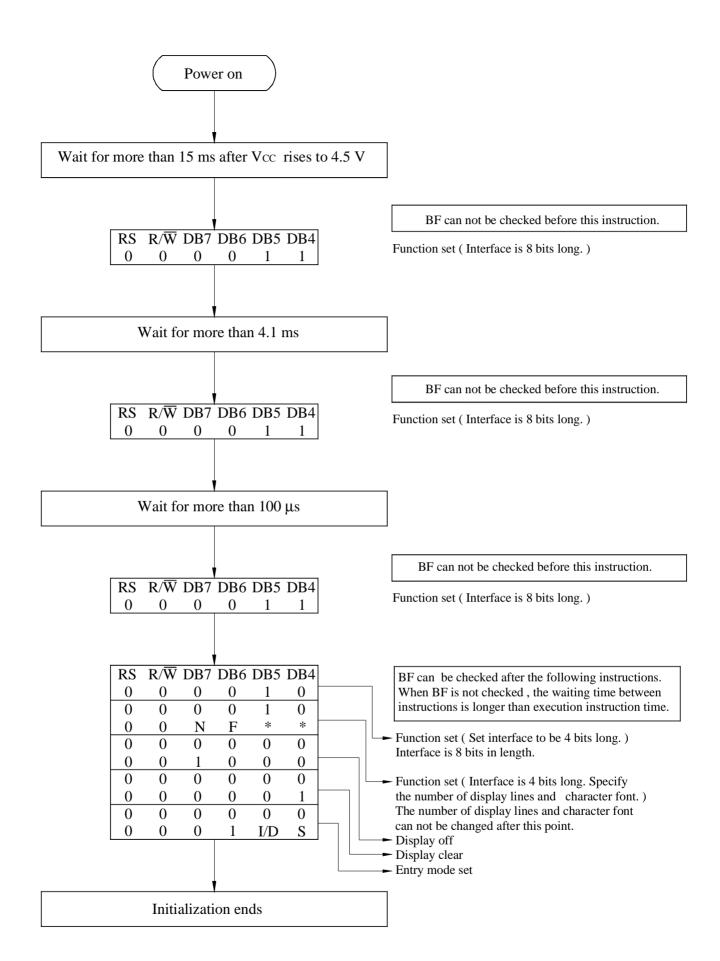
NOTE: \*VOL1 is assumed to be 0.8V at 2 MHZ operation.

Ta=25°C,  $VDD=5.0\pm0.5V$ 

Item	Symbol	Min	Тур	Max	Unit
Enable cycle time	$t_{\rm cycE}$	400	-	-	ns
Enable pulse width (high level)	$PW_{EH}$	150	-	-	ns
Enable rise/fall time	$t_{\rm Er}, t_{\rm Ef}$	-	-	25	ns
Address set-up time (RS, R/W to E)	t <sub>AS</sub>	30	-	-	ns
Address hold time	$t_{AH}$	10	-	-	ns
Data delay time	t <sub>DDR</sub>	-	-	100	ns
Data hold time	t <sub>DHR</sub>	20	-	-	ns

### 13.Initializing of LCM





4-Bit Ineterface

# 14.Quality Assurance

#### **Screen Cosmetic Criteria**

Item	Defect	Judgmen	t Criterion	Partition
		· ·	Clear Acceptable Qty in active area	
		d ≦ 0.1	Disregard	
		0.1 <d≦ 0.2<="" td=""><td>6</td><td></td></d≦>	6	
		0.2 <d≦ 0.3<="" td=""><td>2</td><td></td></d≦>	2	
1	Spots	0.3 <d a<="" at="" b)uto="" be="" d="" holes="" including="" mm="" note:="" pin="" size:="" td="" within=""><td>Minor</td></d>	Minor	
		d ≦ 0.2	Disregard	
		0.2 <d≦ 0.5<="" td=""><td>6</td><td></td></d≦>	6	
		0.5 <d≦ 0.7<="" td=""><td>2</td><td></td></d≦>	2	
		0.7 <d< td=""><td>0</td><td></td></d<>	0	
			cceptable Qty in active area	
		d≦ 0.3	Disregard	
2	Bubbles in Polarize	0.3 <d<b>≦ 1.0</d<b>	3	Minor
		1.0 <d≦ 1.5<="" td=""><td>1</td><td></td></d≦>	1	
		1.5 <d< td=""><td>0</td><td></td></d<>	0	
3	Scratch	In accordance with spots cos reflects on the panel surfac remai	Minor	
4	Allowable Density	Above defects should be sep	Minor	
5	Coloration	Not to be noticeable colorat LCD Back-light type should be ju or	Minor	

# 15.Reliability

### **Content of Reliability Test**

	Environmental T	est	
Test Item	Content of Test	Test Condition	Applicable Standard
High Temperature storage	Endurance test applying the high storage temperature for a long time.	80°C 200hrs	
Low Temperature storage	Endurance test applying the high storage temperature for a long time.	-30°C 200hrs	
High Temperature Operation	Endurance test applying the electric stress (Voltage & Current) and the thermal stress to the element for a long time.	70°C 200hrs	
Low Temperature Operation	Endurance test applying the electric stress under low temperature for a long time.	-20°C 200hrs	
High Temperature/ Humidity Storage	Endurance test applying the high temperature and high humidity storage for a long time.	80°C,90%RH 96hrs	
High Temperature/ Humidity Operation	Endurance test applying the electric stress (Voltage & Current) and temperature / humidity stress to the element for a long time.	70°C,90%RH 96hrs	
Temperature Cycle	Endurance test applying the low and high temperature cycle.  -30°C 25°C 80°C  30min 5min 30min 1 cycle	-30°C/80°C 10 cycles	
	Mechanical Tes	t	
Vibration test	Endurance test applying the vibration during transportation and using.	10~22Hz→ 1.5mmp-p 22~500Hz→ 1.5G Total 0.5hrs	
Shock test	Constructional and mechanical endurance test applying the shock during transportation.	50G Half sign wave 11 msedc 3 times of each direction	
Atmospheric pressure test	Endurance test applying the atmospheric pressure during transportation by air.	115mbar 40hrs	
	Others		
Static electricity test	Endurance test applying the electric stress to the terminal.	VS=800V,RS=1.5kΩ CS=100pF 1 time	

<sup>\*\*\*</sup>Supply voltage for logic system=5V. Supply voltage for LCD system =Operating voltage at 25°C

# 16.Backlight Information

## Specification

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	TEST CONDITION
Supply Current	ILED	_	100		mA	V=4.2V
Supply Voltage	V	-	4.2	4.6	V	-
Reverse Voltage	VR	-	-	8	V	-
Luminous Intensity	IV		60	-	CD/M <sup>2</sup>	ILED=100mA
Wave Length	λр	-	570	-	nm	ILED=100mA
Life Time	-	-	100000	-	Hr.	V≦ 4.6V
Color	Yellow C	Freen		1		